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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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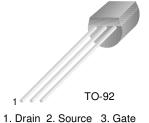




J304

N-Channel RF Amplifier

- · This device is designed for electronic switching applications such as low ON resistance analog switching.
- · Sourced from process 50.



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings* T_C=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DG}	Drain-Gate Voltage	30	V
V_{GS}	Gate-Source Voltage	-30	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

^{*} This ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Charac	Off Characteristics					
V _{(BR)GSS}	Gate-Source Breakdwon Voltage	$I_G = -1.0 \mu A, V_{DS} = 0$	-30			V
I _{GSS}	Gate Reverse Current	$V_{GS} = -20V, V_{DS} = 0$			-100	pА
V _{GS} (off)	Gate-Source Cutoff Voltage	$V_{DS} = 15V, I_D = 1.0nA$	-2.0		-6.0	V
On Characteristics						
I _{DSS}	Zero-Gate Voltage Drain Current	V _{DS} = 15V, VGS = 0	5.0		15	mA
gfs	Forward Transconductance	$V_{GS} = 0V, V_{DS} = 15V, f = 1KHz$	4500		7500	μS
goss	Output Conductance	$V_{GS} = 0V, V_{DS} = 15V, f = 1KHz$			50	μS

Thermal Characteristics $T_A=25$ °C unless otherwise noted

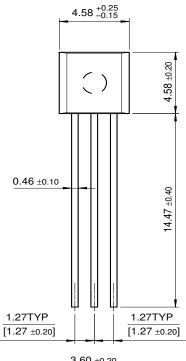
Symbol	Parameter	Max.	Units
P_{D}	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

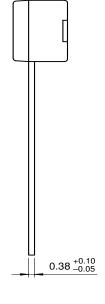
^{*} Device mounted on FR-4 PCB 1.5" × 1.6" × 0.06"

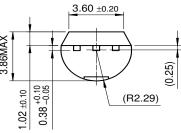
These rating are based on a maximum junction temperature of 150 degrees C.
These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Package Dimensions

TO-92







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Rev. I1

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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